

L Number	Hits	Search Text	DB	Time stamp
71	29	((257/571,583,586,588,592,616).CCLS.) and (base emitter) and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:46
72	0	((438/419,420).CCLS.) and (base emitter) and (epi epitaxy epitaxial epitaxially) and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:46
73	24	((((257/571,583,586,588,592,616).CCLS.) and (base emitter)) and @pd>19771101) and (epi epitaxy epitaxial epitaxially)) and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:46
74	20	(US-4985744-\$ US-4916083-\$ or US-5316957-\$ or US-4847670-\$).did. or (EP-290763-\$).did. or (JP-05175222-\$).did. or "5017990"	USPAT; EPO; JPO	2004/03/23 15:47
75	3	((US-4980304-\$ or US-4985744-\$ or US-5017990-\$ or US-4895744-\$ or US-4847670-\$ or US-4916083-\$ or US-5316957-\$ or US-3697827-\$ or US-6329265-\$ or US-3582724-\$ or US-3600651-\$ or US-3614553-\$ or US-3631307-\$ or US-3665266-\$ or US-4451843-\$ or US-4042947-\$ or US-4339767-\$ or US-4428111-\$ or US-4437897-\$ or US-4504332-\$ or US-4574469-\$ or US-4975381-\$).did. or (EP-290763-\$ or EP-290763-\$).did. or (JP-05175222-\$).did.) and (SiGe or silicon near germanium)	USPAT; US-PGPUB	2004/03/23 15:48
76	55	base near4 (SiGe or silicon near germanium) and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:48
77	56	base near4 (SiGe or silicon near germanium) and @pd>20031130	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/03/23 15:49
78	26	extrinsic adj base and intrinsic adj base and @pd>20031130	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/03/23 15:50
79	47	((257/571,583,586,588,592,616).CCLS. or (438/419,420).CCLS.) and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:50
80	0	"5017990" and @pd>20031130	USPAT; US-PGPUB	2004/03/23 15:51
82	6	blanket adj epitaxy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:10
83	1	008383.ap.	US-PGPUB	2004/03/23 15:54
84	867	((257/571,583,586,588,592,616).CCLS.) and (base emitter) and @pd>19771101	USPAT; US-PGPUB	2004/03/23 16:08
94	5	(blanket adj epitaxy) and (silicon adj germanium SiGe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:11
95	2	(blanket adj epitaxy) and (silicon adj germanium SiGe) near4 intrinsic adj base	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:12
96	4	(blanket adj epitaxy) and (silicon adj germanium SiGe) near6 base	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:14
97	4	((blanket adj epitaxy) and (silicon adj germanium SiGe) near6 base) and intrinsic adj base	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:31
98	4	((blanket adj epitaxy) and (silicon adj germanium SiGe) near6 base) and intrinsic adj base and emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/23 16:31
99	2	(US-20030057458-\$ or US-20030109109-\$).did.	US-PGPUB	2004/03/23 16:51
100	2	(US-20030057458-\$ or US-20030109109-\$).did.	DERWENT	2004/03/23 16:51